### **SEMICONDUCTOR**

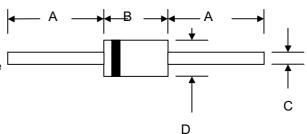
### **6.0A SUPER-FAST RECTIFIER**

#### Green Products

# Data Sheet 4822, Rev.—

#### **Features**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Green Products in Compliance with the RoHS Directive



#### **Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per
  - MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Epoxy: UL 94V-O rate flame retardant

DO-201AD										
Dim	Min	Max	Min	Max						
Α	25.4	_	1.000	_						
В	8.50	9.50	0.335	0.374						
С	1.20	1.30	0.047	0.051						
D	5.0	5.60	0.197	0.220						
	ln ı	mm	In inch							

### Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	SF61-G	SF62-G	SF63-G	SF64-G	SF65-G	SF66-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		Vrrm Vrwm Vr	50	100	150	200	300	400	٧
RMS Reverse Voltage		VR(RMS)	35	70	105	140	210	280	V
Average Rectified Output Current (Note 1)	lo	6.0						Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	150						Α
Forward Voltage	@I <sub>F</sub> = 6.0A	VFM	0.975 1.3					V	
Peak Reverse Current At Rated DC Blocking Voltage	lгм	5.0 100						μΑ	
Reverse Recovery Time (Note 2)		trr	35						nS
Typical Junction Capacitance (Note 3)		Cj	120				6	0	pF
Operating Temperature Range		Tj	-65 to +125						°C
Storage Temperature Range		Тѕтс	-65 to +150						°C

#### \*Glass passivated forms are available upon request

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

- 2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 1.
- 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

0

25

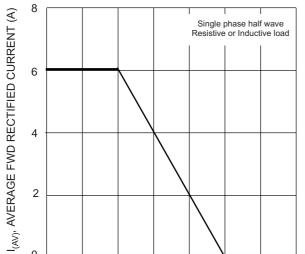
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## Data Sheet 4822, Rev.—



75

Fig. 1 Forward Current Derating Curve





100

125

150

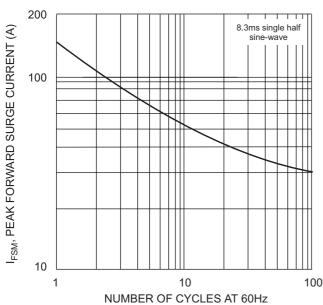
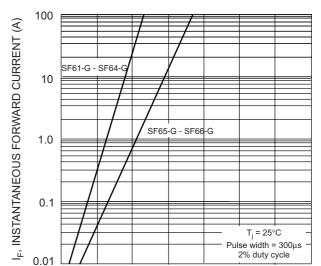


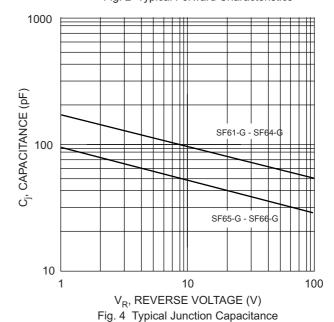
Fig. 3 Peak Forward Surge Current

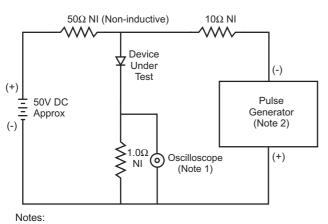


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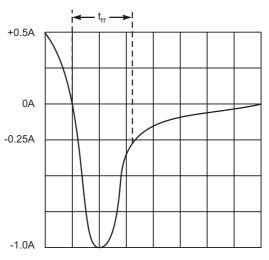
V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics

1.4





- 1. Rise Time = 7.0ns max. Input Impedance =  $1.0M\Omega$ , 22pF.
- 2. Rise Time = 10ns max. Input Impedance =  $50\Omega$ .



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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SF61-G-SF66-G

**6.0A SUPER-FAST RECTIFIER** 

Data Sheet 4822, Rev. -

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